

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	28217	tetraethylorthosilicate or TEOS	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:17
L2	22137	(plasma adj enhanced adj chemical adj vapor adj deposition) or PECVD	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:14
L3	11622	(deposit or depositing or deposited or fill or filling or filled) near4 oxide near8 (trench or trenches or open or opening)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:20
L4	2088177	(partial or partially or half-fill or (half near fill\$6))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:19
L5	353	1 and 2 and 3 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:20
L6	302	5 and ((@ad<"20030130") or (@rlad<"20030130"))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:21
L7	1821	((438/424) or (438/425) or (438/426)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/25 16:21
L8	40	6 and 7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:42
L9	262	6 not 8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/25 16:42